

DATASHEET

4 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER EL817 Series



Features:

- Current transfer ratio
 (CTR: 50~600% at IF =5mA, VCE =5V)
 High isolation voltage between input
- and output (Viso=5000 V rms)
- Creepage distance >7.62 mm
- Operating temperature up to +110°C
- Compact small outline package
- Pb free and RoHS compliant
- UL and cUL approved(No. E214129)
- VDE approved (No. 132249)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved

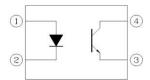
Description

The EL817series of devices each consist of an infrared emitting diodes, optically coupled to a phototransistor detector. They are packaged in a 4-pin DIP package and available in wide-lead spacing and SMD option.

Applications

- Programmable controllers
- System appliances, measuring instruments
- Telecommunication equipments
- Home appliances, such as fan heaters, etc.
- Signal transmission between circuits of different potentials and impedances

Schematic



Pin Configuration

- 1. Anode
- 2. Cathode
- 3. Emitter
- 4. Collector

Absolute Maximum Ratings (Ta=25℃)

| | Parameter | Symbol | Rating | Unit |
|---------------------------------|------------------------------------------------|------------------|------------|-------|
| | Forward current | I _F | 60 | mA |
| | Peak forward current (1us, pulse) | I _{FP} | 1 | А |
| Input | Reverse voltage | V _R | 6 | V |
| | Power dissipation | P _D – | 100 | mW |
| | Derating factor (above T _a = 100°C) | | 2.9 | mW/°C |
| | Power dissipation | P _C – | 150 | mW |
| | Derating factor (above $T_a = 100^{\circ}C$) | | 5.8 | mW/°C |
| Output | Collector current | I _C | 50 | mA |
| | Collector-Emitter voltage | V _{CEO} | 35 | V |
| | Emitter-Collector voltage | V_{ECO} | 6 | V |
| Total Power Dissipation | | P _{TOT} | 200 | mW |
| Isolation Voltage* ¹ | | V _{ISO} | 5000 | V rms |
| Operating Temperature | | T _{OPR} | -55 to 110 | °C |
| Storage Temperature | | T _{STG} | -55 to 125 | °C |
| Soldering | Temperature* ² | T _{SOL} | 260 | °C |

Notes:

*1 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1, 2 are shorted together, and pins 3, 4 are shorted together. *2 For 10 seconds

Electro-Optical Characteristics (Ta=25°C unless specified otherwise)

| Input | | | | | | | | |
|----------------------------------------|-------------|----------------------|--------------------|------|------|------|---------------------------------------------------------------------------|--|
| Parar | neter | Symbol | Min. | Тур. | Max. | Unit | Condition | |
| Forward Vo | ltage | V _F | - | 1.2 | 1.4 | V | I _F = 20mA | |
| Reverse Cu | rrent | I _R | - | - | 10 | μA | | |
| Input capac | itance | C _{in} | - | 30 | 250 | pF | V = 0, f = 1kHz | |
| Output | | | | | | | | |
| Parar | neter | Symbol | Min | Тур. | Max. | Unit | Condition | |
| Collector-Er current | nitter dark | I _{CEO} | - | - | 100 | nA | V _{CE} = 20V, I _F = 0mA | |
| Collector-Er breakdown | | BV_{CEO} | 35 | - | - | V | I _C = 0.1mA | |
| Emitter-Collector breakdown voltage | | BV_{ECO} | 6 | - | - | V | I _E = 0.1mA | |
| Transfer C | haracterist | ics | | | | | | |
| Parar | neter | Symbol | Min | Тур. | Max. | Unit | Condition | |
| | EL817 | - - - CTR | 50 | - | 600 | - % | I _F = 5mA ,V _{CE} = 5V | |
| | EL817A | | 80 | - | 160 | | | |
| Current | EL817B | | 130 | - | 260 | | | |
| Transfer | EL817C | | 200 | - | 400 | | | |
| ratio | EL817D | | 300 | - | 600 | | | |
| | EL817X | | 100 | - | 200 | | | |
| | EL817Y | | 150 | - | 300 | | | |
| Collector-Emitter saturation voltage | | V _{CE(sat)} | - | 0.1 | 0.2 | V | I _F = 20mA ,I _C = 1mA | |
| Isolation resistance | | R _{IO} | 5×10 ¹⁰ | - | - | Ω | V _{IO} = 500Vdc, 40~60% R.H. | |
| Floating capacitance | | C _{IO} | - | 0.6 | 1.0 | pF | V _{IO} = 0, f = 1MHz | |
| Cut-off frequency | | fc | - | 80 | - | kHz | V _{CE} = 5V, I _C = 2mA R _L = 100Ω, -3dB | |
| Rise time | | t _r | - | 4 | 18 | μs | $V_{CE} = 2V, I_{C} = 2mA,$ | |
| | | | | | | | $R_L = 100\Omega$ | |

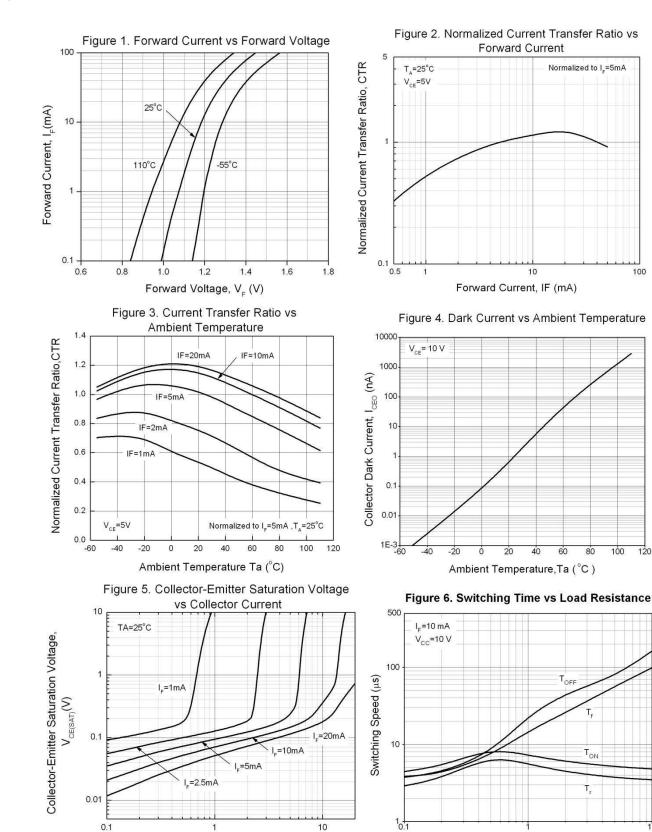
* Typical values at $T_a = 25$ °C

100

100 120

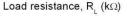
80

Τ.



Collector Current, I_c (mA)

Typical Electro-Optical Characteristics Curves



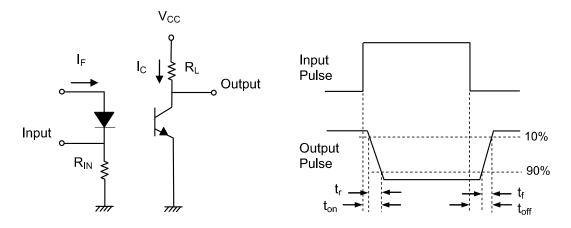


Figure 7. Switching Time Test Circuit & Waveforms

Order Information

Part Number

EL817X(Y)(Z)-FV

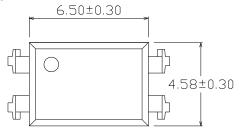
Note

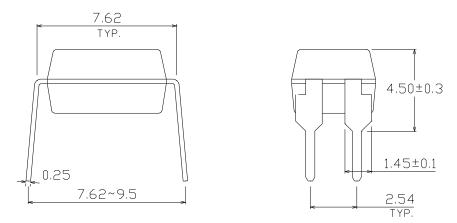
- X Y Z = Lead form option (S, S1, S2, M or none) = CTR Rank (A, B, C, D, X, Y or none)
- = Tape and reel option (TA, TB, TU, TD or none).
- F V = Lead frame option (F: Iron, None: copper)
- = VDE safety (optional).

| Option | Description | Packing quantity |
|---------|---------------------------------------------------------------|---------------------|
| None | Standard DIP-4 | 100 units per tube |
| М | Wide lead bend (0.4 inch spacing) | 100 units per tube |
| S (TA) | Surface mount lead form + TA tape & reel option | 1000 units per reel |
| S (TB) | Surface mount lead form + TB tape & reel option | 1000 units per reel |
| S1 (TA) | Surface mount lead form (low profile) + TA tape & reel option | 1000 units per reel |
| S1 (TB) | Surface mount lead form (low profile) + TB tape & reel option | 1000 units per reel |
| S2 (TA) | Surface mount lead form (Gull-wing) + TA tape & reel option | 1000 units per reel |
| S2 (TB) | Surface mount lead form (Gull-wing) + TB tape & reel option | 1000 units per reel |
| S (TU) | Surface mount lead form + TU tape & reel option | 1500 units per reel |
| S (TD) | Surface mount lead form + TD tape & reel option | 1500 units per reel |
| S1 (TU) | Surface mount lead form (low profile) + TU tape & reel option | 1500 units per reel |
| S1 (TD) | Surface mount lead form (low profile) + TD tape & reel option | 1500 units per reel |

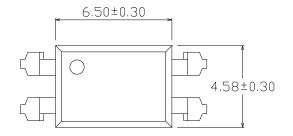
Package Dimension (Dimensions in mm)

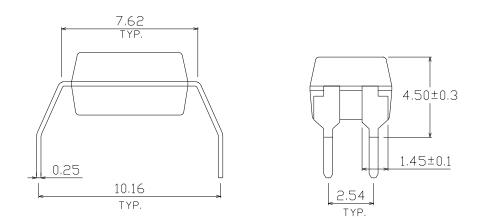
Standard DIP Type





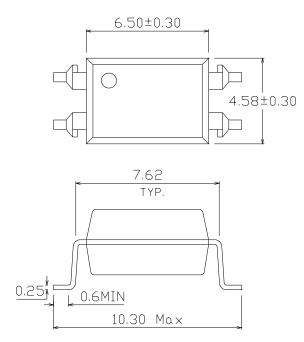
Option M Type

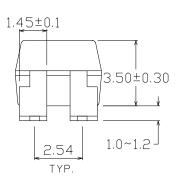




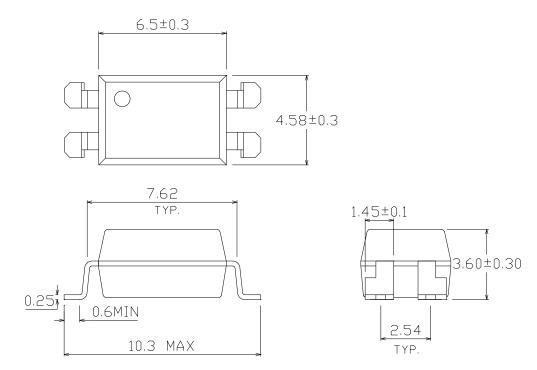


Option S Type

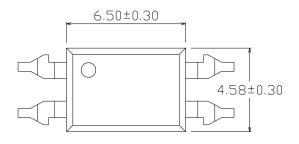


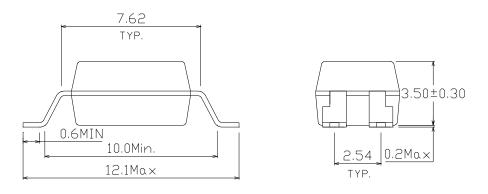


Option S1 Type



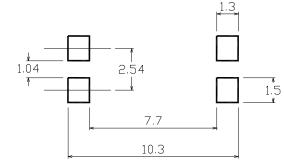
Option S2 Type



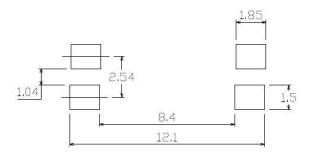


Recommended pad layout for surface mount leadform

For S and S1 option



For S2 option





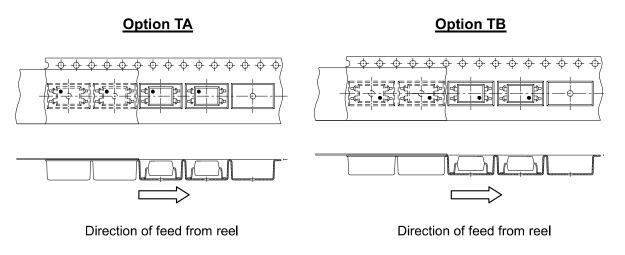
Device Marking



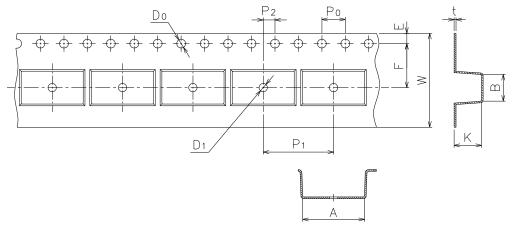
Notes

| EL | denotes EVERLIGHT |
|-----|------------------------------------------------|
| 817 | denotes Device Number |
| F | denotes Factory Code (G: China and Green part) |
| R | denotes CTR Rank (A, B, C, D , X , Y or none) |
| Y | denotes 1 digit Year code |
| WW | denotes 2 digit Week code |
| V | denotes VDE (optional) |

Tape & Reel Packing Specifications



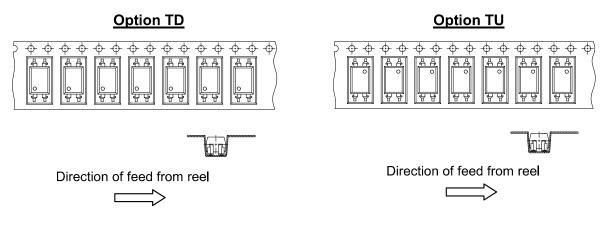
Tape dimensions



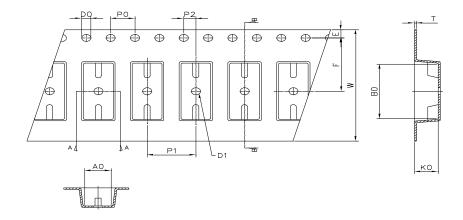
| Dimension No. | Α | В | Do | D1 | E | F |
|----------------------|-----------|----------|---------|----------|----------|----------|
| Dimension (mm) S | 10.5±0.1 | 4.65±0.1 | 1.5±0.1 | 1.50±0.1 | 1.75±0.1 | 7.5±0.1 |
| Dimension (mm) S1 | 10.5±0.1 | 4.65±0.1 | 1.5±0.1 | 1.50±0.1 | 1.75±0.1 | 7.5±0.1 |
| Dimension (mm) S2 | 12.15±0.1 | 4.65±0.1 | 1.5±0.1 | 1.50±0.1 | 1.75±0.1 | 7.5±0.1 |
| Dimension No. | Ро | P1 | P2 | t | w | к |
| Dimension (mm) S | 4.0±0.1 | 12.0±0.1 | 2.0±0.1 | 0.4±0.1 | 16.0±0.3 | 5.05±0.1 |
| Dimension (mm) S1 | 4.0±0.1 | 12.0±0.1 | 2.0±0.1 | 0.4±0.1 | 16.0±0.3 | 4.75±0.1 |
| Dimension (mm) S2 | 4.0±0.1 | 16.0±0.1 | 2.0±0.1 | 0.4±0.1 | 16.0±0.3 | 3.90±0.1 |

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Tape & Reel Packing Specifications



Tape dimensions

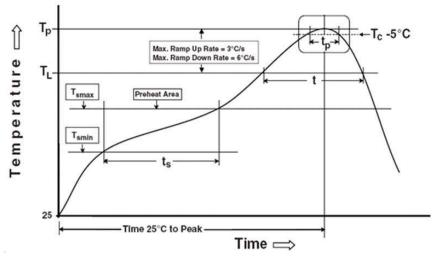


| Dimension No. | Ао | Во | Do | D1 | Е | F |
|------------------------|----------|-----------|----------|----------|-----------|----------|
| Dimension (mm) S.S1 | 4.90±0.1 | 10.40±0.1 | 1.5±0.1 | 1.50±0.1 | 1.75±0.1 | 7.50±0.1 |
| Dimension No. | Ро | P1 | P2 | t | w | Ко |
| Dimension (mm) S.S1 | 4.00±0.1 | 8.00±0. | 2.00±0.1 | 0.40±0.1 | 16.00±0.3 | 4.60±0.1 |

Precautions for Use

1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note:

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Reference: IPC/JEDEC J-STD-020D

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Preheat

| Temperature min (T _{smin}) | 150 °C |
|---------------------------------------------------------------------------------------------------------------------------------|-----------------------------------|
| Temperature max (T _{smax}) | 200°C |
| Time (T _{smin} to T _{smax}) (t _s) Average ramp-up rate (T _{smax} to T _p) | 60-120 seconds 3 °C/second max |
| Other | |
| Liquidus Temperature (T_L) | 217 °C |
| Time above Liquidus Temperature (t $_{L}$) | 60-100 sec |
| Peak Temperature (T _P) | 260°C |
| Time within 5 °C of Actual Peak Temperature: T_P - 5°C | 30 s |
| Ramp- Down Rate from Peak Temperature | 6°C /second max. |
| Time 25°C to peak temperature Reflow times | 8 minutes max. 3 times |

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